

Features

- Low On-resistance and Low Conduction Loss
- Super Junction technology for High Voltage Application
- Soft Switching with Fast Reverse Recovery Diode
- Ultra Low Gate Charge Cause Lower Driving Requirement
- Epoxy Meets UL 94 V-0 Flammability Rating
- Halogen Free."Green "Device^(Note 1)
- Lead Free Finish/RoHS Compliant. "P" Suffix Designates RoHS Compliant. See Ordering Information

Maximum Ratings

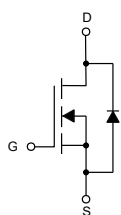
- Operating Junction Temperature Range : -55°C to +150°C
- Storage Temperature Range: -55°C to +150°C
- Thermal Resistance Junction to Ambient,Max^(Note 2): 62°C/W
- Thermal Resistance Junction to Case,Max : 0.56°C/W

| Parameter | Symbol | Value | Unit |
|---|----------|-------------------------|------|
| Drain-Source Voltage | V_{DS} | 600 | V |
| Gate-Source Voltage | V_{GS} | ±30 | V |
| Continuous Drain Current | I_D | $T_C=25^\circ\text{C}$ | 58 |
| | | $T_C=100^\circ\text{C}$ | 36.7 |
| Pulsed Drain Current ^(Note 3) | I_{DM} | 232 | A |
| Total Power Dissipation, $T_C=25^\circ\text{C}$ | P_D | 223 | W |
| Single Avalanche Energy ^(Note 4) | E_{AS} | 2371 | mJ |

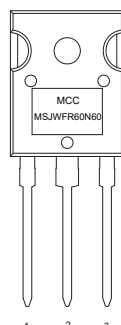
Note:

1. Halogen free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <100ppm antimony compounds.
2. Device in a still air environment with $T_A=25^\circ\text{C}$.
3. Repetitive rating; pulse width limited by max. junction temperature.
4. Starting $T_J=25^\circ\text{C}$, $V_{DD}=50\text{V}$, $I_{AS}=15.4\text{A}$.

Internal Structure and Marking Code



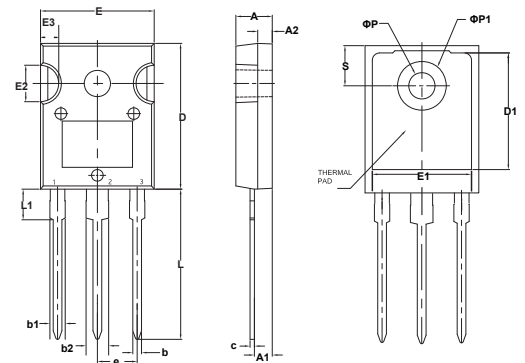
1. Gate
2. Drain
3. Source



Device Code: MSJWFR60N60

N-CHANNEL Super-Junction Power MOSFET

TO-247AB(E)



DIMENSIONS

| DIM | INCHES | | mm | | NOTE |
|-----|--------|-------|-------|-------|------|
| | MIN | MAX | MIN | MAX | |
| A | 0.189 | 0.205 | 4.80 | 5.20 | |
| A1 | 0.087 | 0.102 | 2.20 | 2.60 | |
| A2 | 0.059 | 0.098 | 1.50 | 2.50 | |
| b | 0.035 | 0.055 | 0.90 | 1.40 | |
| b1 | 0.063 | 0.094 | 1.60 | 2.40 | |
| b2 | 0.098 | 0.138 | 2.50 | 3.50 | |
| c | 0.014 | 0.035 | 0.35 | 0.90 | |
| D | 0.776 | 0.815 | 19.70 | 20.70 | |
| D1 | 0.512 | - | 13.00 | - | |
| E | 0.598 | 0.630 | 15.20 | 16.00 | |
| E1 | 0.528 | - | 13.40 | - | |
| E2 | 0.177 | 0.217 | 4.50 | 5.50 | |
| E3 | 0.091 | 0.106 | 2.30 | 2.70 | |
| e | 0.215 | | 5.45 | | TYP |
| L | 0.768 | 0.827 | 19.50 | 21.00 | |
| L1 | - | 0.169 | - | 4.30 | |
| P | 0.134 | 0.150 | 3.40 | 3.80 | Φ |
| P1 | - | 0.291 | - | 7.40 | Φ |
| S | 0.217 | | 5.50 | | TYP |

Electrical Characteristics ($T_J = 25^\circ\text{C}$ unless otherwise specified)

| Parameter | Symbol | Test Conditions | Min | Typ | Max | Unit |
|-------------------------------------|---------------|---|-----|------|-----------|------------|
| Static Characteristics | | | | | | |
| Drain-Source Breakdown Voltage | $V_{(BR)DSS}$ | $V_{GS}=0V, I_D=1mA$ | 600 | | | V |
| Gate-Source Leakage Current | I_{GSS} | $V_{DS}=0V, V_{GS}=\pm 30V$ | | | ± 100 | nA |
| Zero Gate Voltage Drain Current | I_{DSS} | $V_{DS}=600V, V_{GS}=0V$ | | | 10 | μA |
| Gate-Threshold Voltage | $V_{GS(th)}$ | $V_{DS}=V_{GS}, I_D=5mA$ | 3 | 4 | 5 | V |
| Drain-Source On-Resistance | $R_{DS(on)}$ | $V_{GS}=10V, I_D=37.5A$ | | 26.5 | 30 | m Ω |
| Gate Resistance | R_g | $f=1MHz, \text{open drain}$ | | 1 | | Ω |
| Diode Characteristics | | | | | | |
| Diode Forward Voltage | V_{SD} | $V_{GS}=0V, I_S=37.5A$ | | 0.9 | 1.2 | V |
| Reverse Recovery Time | t_{rr} | $V_R=400V, I_F=37.5A$ $di_F/dt=100A/\mu s$ | | 165 | | ns |
| Reverse Recovery Charge | Q_{rr} | | | 1450 | | nC |
| Peak Reverse Recovery Current | I_{rrm} | | | 15 | | A |
| Dynamic Characteristics | | | | | | |
| Input Capacitance | C_{iss} | $V_{DS}=100V, V_{GS}=0V, f=1MHz$ | | 8078 | | pF |
| Output Capacitance | C_{oss} | | | 300 | | |
| Output capacitance - energy related | $C_{o(er)}$ | $V_{DS}=0 \text{ to } 400V, V_{GS}=0V$ | | 301 | | |
| Output capacitance - time related | $C_{o(tr)}$ | | | 1950 | | |
| Total Gate Charge | Q_g | $V_{DS}=400V, V_{GS}=10V, I_D=37.5A$ | | 197 | | nC |
| Gate-Source Charge | Q_{gs} | | | 49 | | |
| Gate-Drain Charge | Q_{gd} | | | 95 | | |
| Turn-On Delay Time | $t_{d(on)}$ | $V_{DD}=400V, V_{GS}=10V$ $R_G=2.7\Omega, I_D=37.5A$ | | 73 | | ns |
| Turn-On Rise Time | t_r | | | 26 | | |
| Turn-Off Delay Time | $t_{d(off)}$ | | | 86 | | |
| Turn-Off Fall Time | t_f | | | 10 | | |

Typical Characteristics ($T_J=25^\circ\text{C}$ unless otherwise specified)

Fig. 1 - Typical Output Characteristics

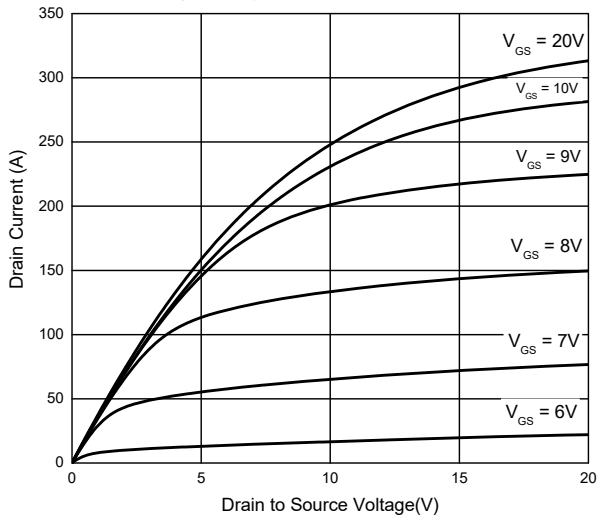


Fig. 2 - Typical Transfer Characteristics

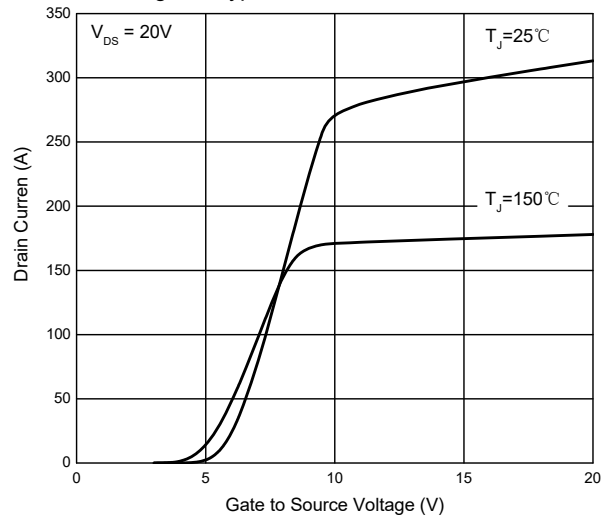


Fig. 3 - On-Resistance vs Gate Bias

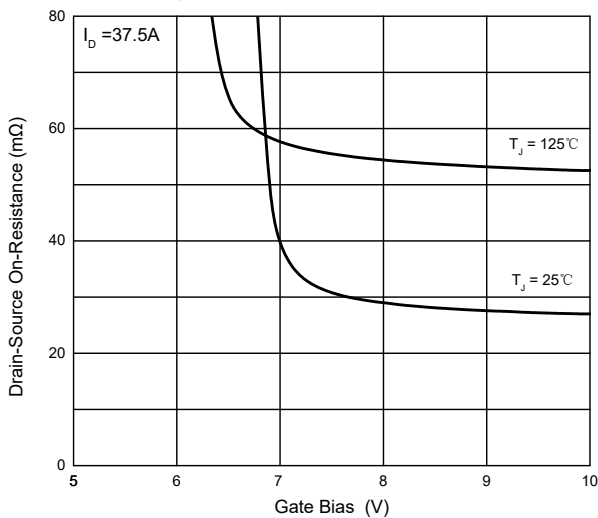


Fig. 4 - On-Resistance vs Drain Current

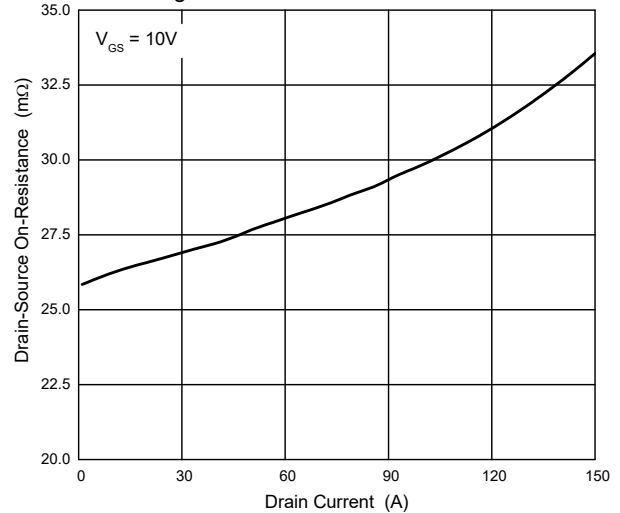


Fig. 5 - Capacitance Characteristic

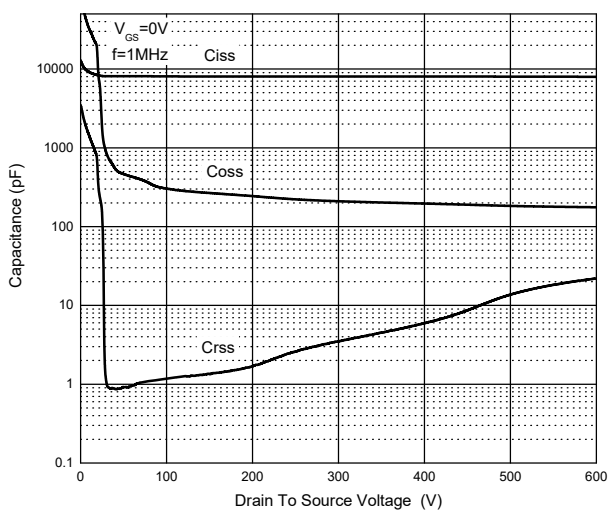
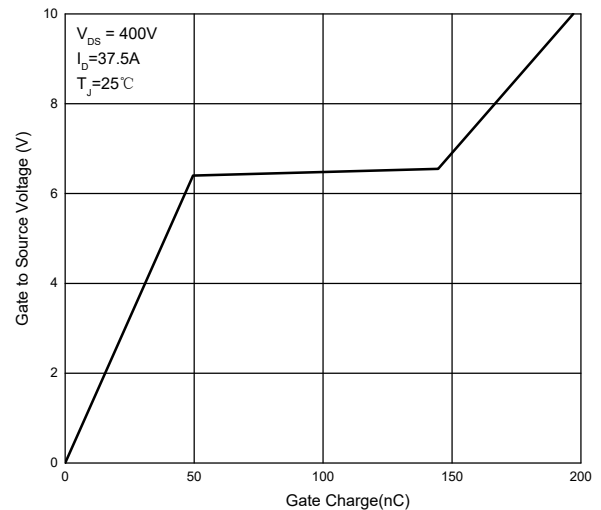


Fig. 6 - Typical Gate Charge



Typical Characteristics ($T_J=25^\circ\text{C}$ unless otherwise specified)

Fig. 7 - Gate-Threshold Voltage vs Junction Temperature

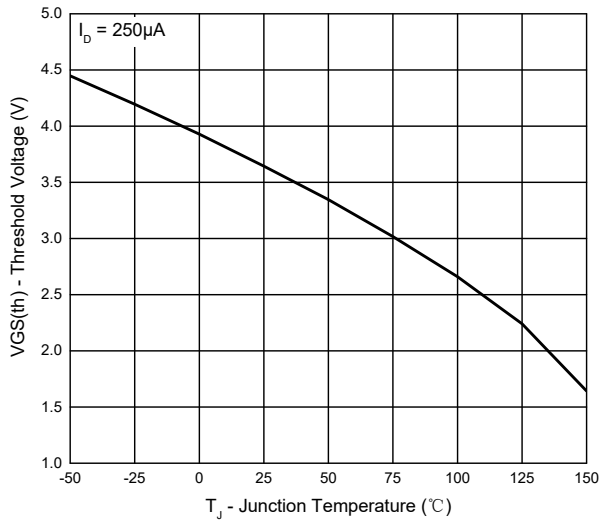


Fig. 8 - Normalized On-Resistance

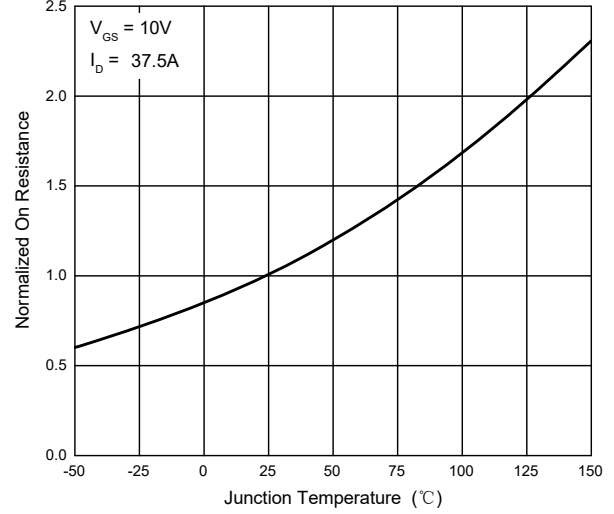


Fig. 9 - Forward Characteristics

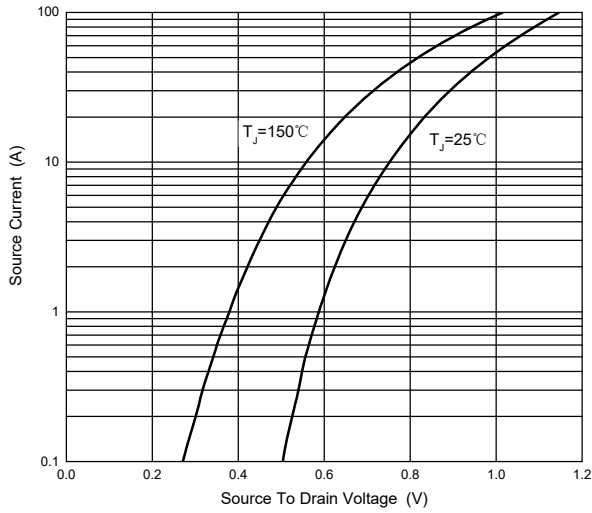


Fig. 10- Drain Current

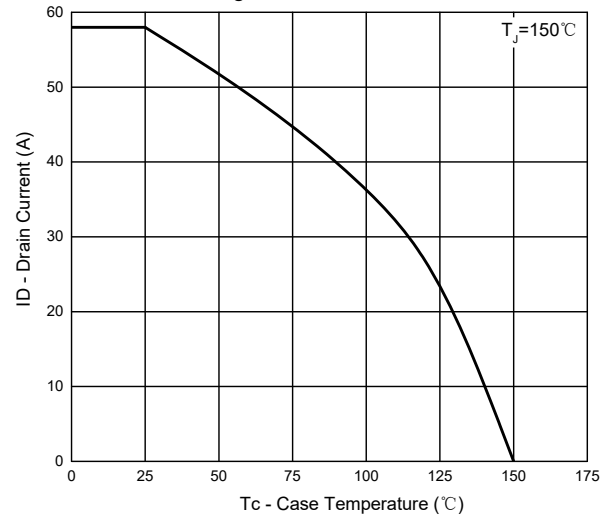


Fig. 11 - Power Dissipation

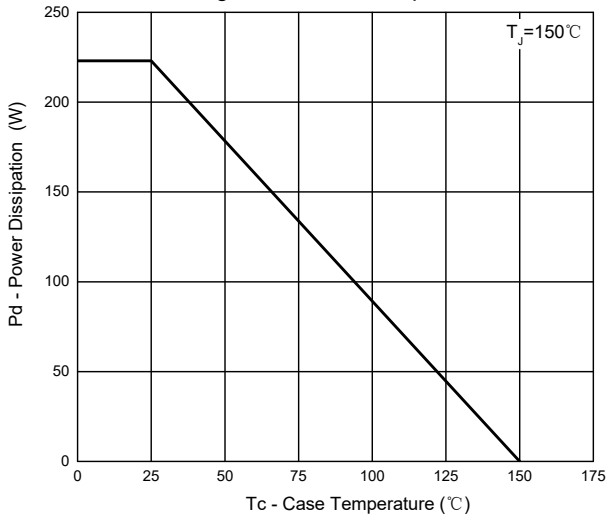
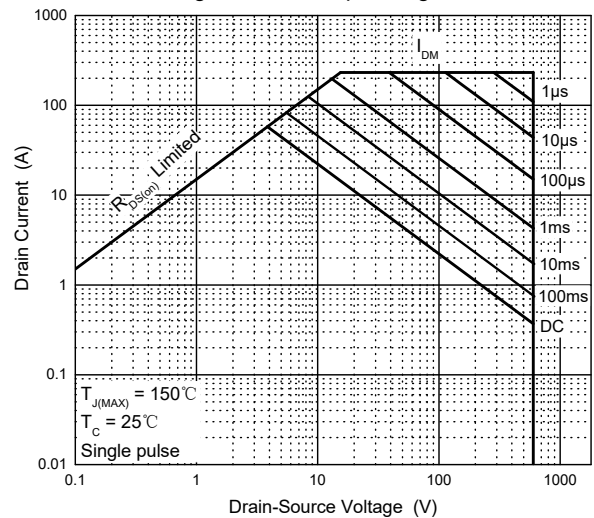
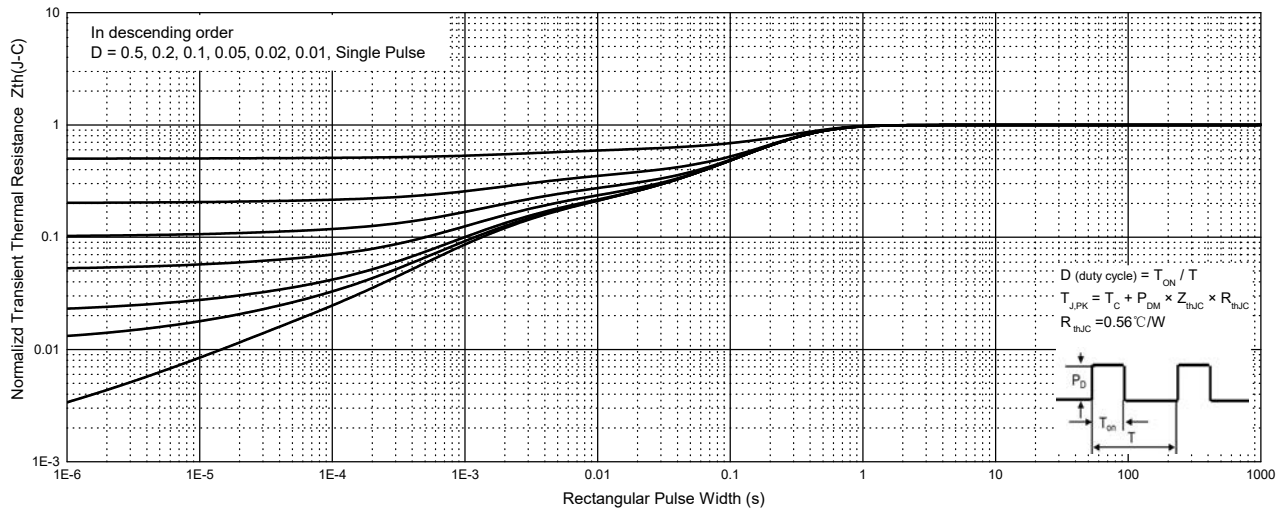


Fig. 12 - Safe Operating Area



Typical Characteristics ($T_J=25^\circ\text{C}$ unless otherwise specified)

Fig.13 - Normalized Transient Thermal Impedance, Junction-Case



Ordering Information

| Device | Packing |
|----------------|--|
| MSJWFR60N60-BP | Tube:30pcs/Tube, 360pcs/Box, 1.8K/Ctn; |

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